

STTH1512

1200 V ultrafast recovery diode

Features

- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- Insulated package: DOP3I
 - Electrical insulation = 2500 V rms
 - Capacitance = 12 pF

Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

Such demanding applications include industrial power supplies, motor control, and similar mission-critical systems that require rectification and freewheeling. These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.

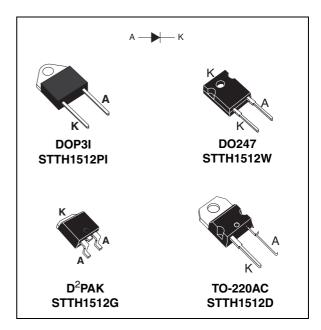


Table 1. Device summary

,			
Symbol	Value		
I _{F(AV)}	15 A		
V _{RRM}	1200 V		
T _j	175 °C		
V _F (typ)	1.20 V		
t _{rr} (typ)	53 ns		

April 2010 Doc ID 12157 Rev 2 1/11

Characteristics STTH1512

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol		Value	Unit		
V _{RRM}	Repetitive peak reverse vo	ltage		1200	V
I _{F(RMS)}	Forward rms current	TO-220AC / DO247 / DO	DP3I / D ² PAK	50	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$	TO-220AC / D ² PAK / T _c = 130 °C		15 A	
. ()	0 = 0.5	DOP3I	T _c = 105 °C		İ
I _{FRM}	Repetitive peak forward current	$t_p = 5 \mu s$, $F = 5 kHz squ$	200	Α	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal	200	Α	
T _{stg}	Storage temperature range			-65 to + 175	°C
T _j	Maximum operating junction temperature			175	°C

Table 3. Thermal parameters

Symbol	Parame	Value	Unit	
В	Junction to case	TO-220AC / D ² PAK / DO247	1.3	°C/W
R _{th(j-c)}	Junction to case	DOP3I	2	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage	T _j = 25 °C	V V			15	μΑ
'R'	current	$T_j = 125 ^{\circ}\text{C}$ $V_R = V_{RRM}$	= 125 °C VR - VRRM		10	100	μΛ
		T _j = 25 °C				2.10	
V _F ⁽²⁾	Forward voltage drop	T _j = 125 °C	I _F = 15 A		1.25	1.90	V
		T _j = 150 °C			1.20	1.80	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation:

$$P = 1.4 \times I_{F(AV)} + 0.027 I_{F}^{2}_{(RMS)}$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

STTH1512 Characteristics

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
A Danier and the second		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/µs,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$			105	ns
^L rr	t _{rr} Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		53	75	115
I _{RM}	Reverse recovery current	$I_F = 15 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s}, \ V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$		20	28	Α
S	Softness factor	$I_F = 15 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s}, \ V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$		1.5		
t _{fr}	Forward recovery time	$I_F = 15 \text{ A}$ $dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_{FR} = 1.5 \text{ x V}_{Fmax}, T_j = 25 ^{\circ}\text{C}$			600	ns
V _{FP}	Forward recovery voltage	$I_F = 15 \text{ A}, dI_F/dt = 50 \text{ A}/\mu\text{s},$ $T_j = 25 ^{\circ}\text{C}$		5.5		V

Figure 1. Conduction losses versus average current

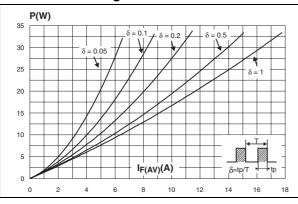


Figure 2. Forward voltage drop versus forward current

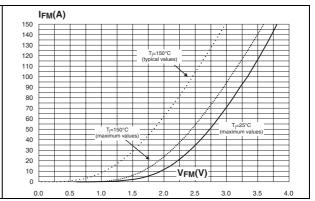
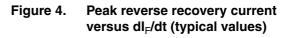
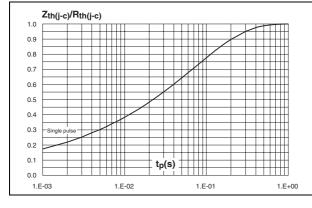
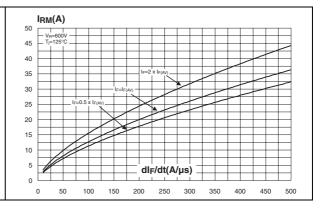


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration



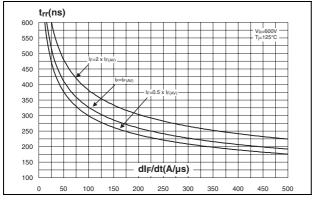




Characteristics STTH1512

Figure 5. Reverse recovery time versus dl_F/dt (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



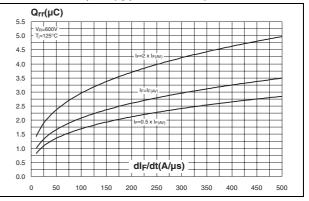
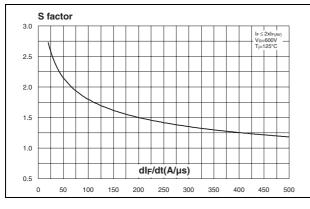


Figure 7. Softness factor versus dl_F/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature



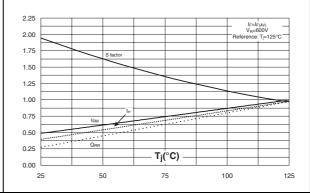
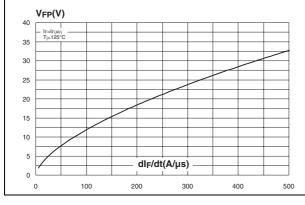
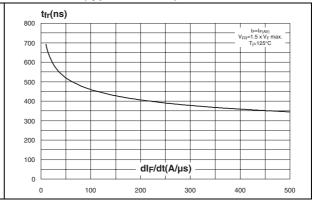


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values)

Figure 10. Forward recovery time versus dl_F/dt (typical values)



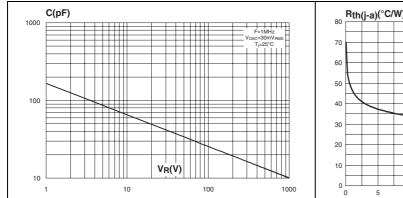


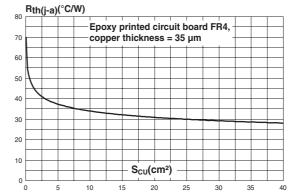
4/11 Doc ID 12157 Rev 2

STTH1512 Characteristics

Figure 11. Junction capacitance versus reverse voltage applied (typical values)

Figure 12. Thermal resistance junction to ambient versus copper surface under each lead





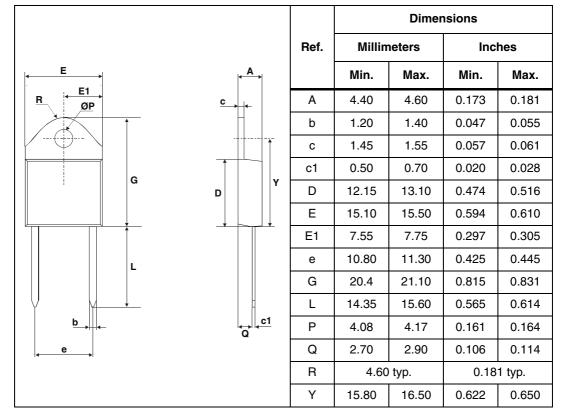
Package information STTH1512

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N⋅m (TO-220AC)
- Recommended torque value: 0.80 N·m (DOP3I)
- Maximum torque value: 1.0 N⋅m (DOP3I)

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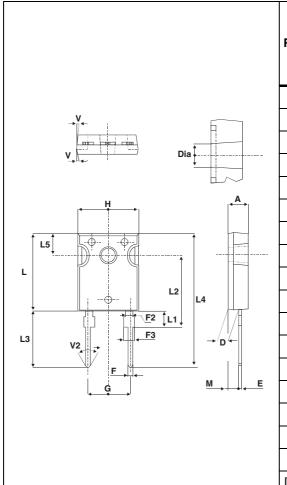
Table 6. DOP3 dimensions



6/11 Doc ID 12157 Rev 2

STTH1512 Package information

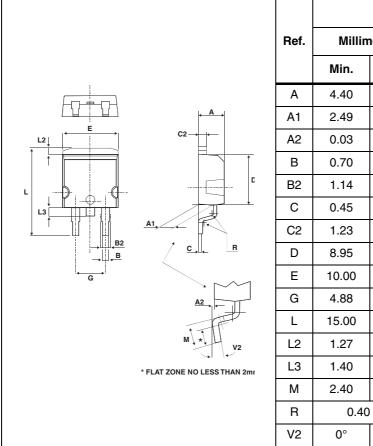
Table 7. DO247 dimensions



	Dimensions					
Ref.	Millimete		fillimeters Inches		Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
Е	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F2		2.00			0.078	
F3	2.00		2.40	0.078		0.094
G		10.90			0.429	
Н	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
L3	14.20		14.80	0.559		0.582
L4		34.60			1.362	
L5		5.50			0.216	
М	2.00		3.00	0.078		0.118
V		5°			5°	
V2		60°			60°	
Dia.	3.55		3.65	0.139		0.143

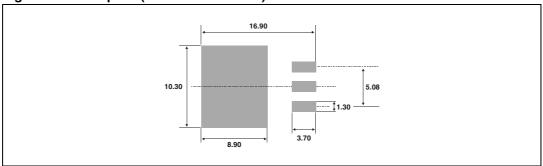
Package information STTH1512

Table 8. D²PAK dimensions



		Dimer	nsions	
Ref.	Millim	neters	Inc	hes
	Min. Ma		Min.	Max.
Α	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
В	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
С	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
Е	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
М	2.40	3.20	0.094	0.126
R	0.40	typ.	0.016	6 typ.
V2	0°	8°	0°	8°

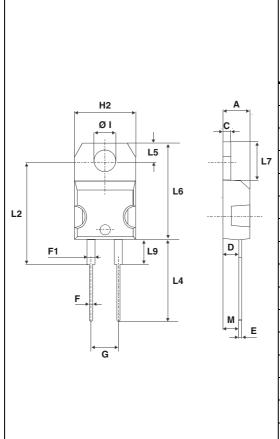
Figure 13. Footprint (dimensions in mm)



8/11 Doc ID 12157 Rev 2

STTH1512 Package information

Table 9. TO-220AC dimensions



	Dimensions					
Ref.	Millim	neters	Inc	hes		
	Min. Max.		Min.	Max.		
Α	4.40	4.60	0.173	0.181		
С	1.23	1.32	0.048	0.051		
D	2.40	2.72	0.094	0.107		
Е	0.49	0.70	0.019	0.027		
F	0.61	0.88	0.024	0.034		
F1	1.14	1.70	0.044	0.066		
G	4.95	5.15	0.194	0.202		
H2	10.00	10.40	0.393	0.409		
L2	16.40	O typ.	0.645	ō typ.		
L4	13.00	14.00	0.511	0.551		
L5	2.65	2.95	0.104	0.116		
L6	15.25	15.75	0.600	0.620		
L7	6.20	6.60	0.244	0.259		
L9	3.50	3.93	0.137	0.154		
М	2.6	typ.	0.102	2 typ.		
Diam. I	3.75	3.85	0.147	0.151		

3 Ordering information

Table 10. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH1512D	STTH1512D	TO-220AC	1.86g	50	Tube
STTH1512PI	STTH1512PI	DOP3I	4.46 g	30	Tube
STTH1512W	STTH1512W	DO-247	4.4 g	30	Tube
STTH1512G	STTH1512G	D ² PAK	1.48 g	50	Tube
STTH1512G-TR	STTH1512G	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 11. Document revision history

Date	Revision	Changes
02-Mar-2006	1	Initial release.
19-Apr-2010	2	Updated I _{FSM} in <i>Table 2</i> from 150 A to 200 A. Updated ECOPACK statement.

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Doc ID 12157 Rev 2

11/11